TOSHIBA LED LAMP GAP GREEN LIGHT EMISSION

# TLGC135AP

#### PANEL CIRCUIT INDICATOR

Without stand-offs

 All Plastic Mold Type Clear Transparent Lens

High Intensity & Moderate Radiation Angle
 Half Angle = ±15deg. (Typ.)

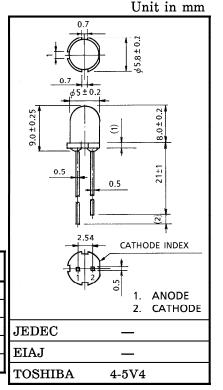
(Limits for 50% of I<sub>V</sub>)

Recommended Forward Current: IF=15~20mA (DC)

• Fast Response Time, Capable of Pulse Operation.

### MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Forward Current	${ m I_F}$	40	mA
Reverse Voltage	$ m v_R$	4	V
Power Dissipation	$P_{\mathbf{D}}$	120	mW
Operating Temperature Range	$T_{ m opr}$	-20~85	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-30~100	°C



Weight: 0.33g

## ELECTRO-OPTICAL CHARACTERISTICS (Ta = 25°C)

CHA	RACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Forward V	oltage	$ m V_{ m F}$	I <sub>F</sub> =20mA	_	2.15	2.8	V
Reverse Cu	ırrent	$I_{ m R}$	$V_R=4V$	-	_	5	$\mu$ A
Luminous Intensity	TLGC135AP			47.6	150	_	
	TLGC135AP (MN)	${ m I}_{ m V}$	I <sub>F</sub> =20mA (Note)	47.6	_	230	mcd
	TLGC135AP (NP)			85.0	_	414	
Peak Emission Wave Length		$\lambda_{\mathbf{p}}$	$I_{ m F} = 20 { m mA}$	_	567		nm
Spectral Line Half Width		Δλ	$I_{\mathbf{F}} = 20 \text{mA}$	_	25	_	nm

(Note) Rank selection carried out under next standard range respectively, although it needs  $\pm 15\%$  sdditionary for guaranteed limits.

M: 56~112mcd, N: 100~200mcd, P: 180~360mcd

Each rank products is classified by package unit, and (MN) includes M and N. (NP) includes N and P.

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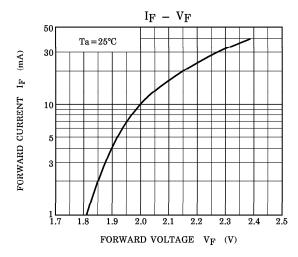
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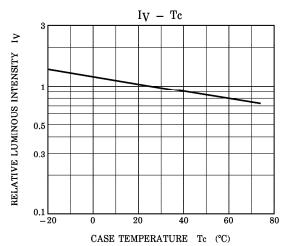
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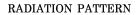
## **PRECAUTION**

Please be careful of the followings

- Soldering temperature: 260°C MAX. Soldering time: 3s MAX. (Soldering portion of lead: up to 2mm from the body of the device)
- If the lead is formed, the lead should be formed up to 5mm from the body of the device without forming stress to the resin. Soldering should be performed after lead forming.







 $Ta = 25^{\circ}C$ 

